

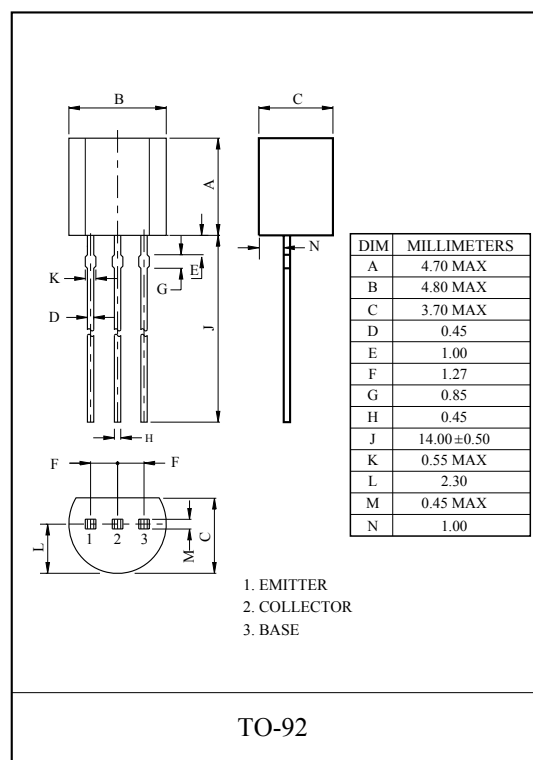
GENERAL PURPOSE APPLICATION.
SWITCHING APPLICATION.

FEATURES

- Excellent h_{FE} Linearity.
: $h_{FE}(I_C=0.1mA)/h_{FE}(I_C=2mA)=0.95(Typ.)$
- Low Noise : $NF=1dB(Typ.)$. at $f=1kHz$
- Complementary to KTC945.

MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-60	V
Collector-Emitter Voltage	V_{CEO}	-50	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-150	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C



ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-100\mu A, I_E=0$	-60	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-1mA, I_B=0$	-50	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-100\mu A, I_C=0$	-5	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB}=-50V, I_E=0$	-	-	-0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-5V, I_C=0$	-	-	-0.1	μA
DC Current Gain	$h_{FE} (Note)$	$V_{CE}=-6V, I_C=-2mA$	90	-	600	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-100mA, I_B=-10mA$	-	-0.1	-0.3	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=-100mA, I_B=-10mA$	-	-	-1.1	V
Transition Frequency	f_T	$V_{CE}=-10V, I_C=-10mA$	-	300	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V, I_E=0, f=1MHz$	-	4	7	pF
Noise Figure	NF	$V_{CE}=-6V, I_C=-0.1mA, R_g=10k\Omega, f=1kHz$	-	1.0	10	dB

Note : h_{FE} Classification R:90 ~ 180, Q:135 ~ 270, P:200 ~ 400, K:300 ~ 600

